



Product Summary

BV _{DSS}	R _{D1D2 max}	I _D T _A = +25°C
	90mΩ @ V _{GS} = -4.5V	-3.2A
-20V	120mΩ @ V _{GS} = -2.5V	-2.7A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, which makes it ideal for high-efficiency power management applications.

Load Switch

Notes:

- **Power Management Functions**
- Portable Power Adaptors

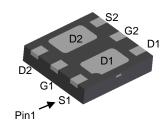
Features

- PCB Footprint of 4mm²
- Low On-Resistance
- Low Input Capacitance
- Low Profile, 0.6mm Maximum Height
- **ESD Protected Gate**
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts gualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @4
- Terminals Connections: See Diagram Below
- Weight: 0.0065 grams (Approximate)





U-DFN2020-6 (Type B)

Bottom View

D2 D1 G2 G1 Gate Protection Protection Diode Diode S1/S2

Internal Schematic

Ordering Information (Note 4)

Part Number	Case	Packaging
DMP2090UFDB-7	U-DFN2020-6 (Type B)	3000/Tape & Reel
DMP2090UFDB-13	U-DFN2020-6 (Type B)	10,000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

Site 1:



E4 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: G = 2019) M = Month (ex: 9 = September)

Date Code Key

Year	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	G	Н		J	К	L	М	N	0	Р	R	S
Month	Jan	Feb	Mar	Apr	Mav	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Site 2:



E4 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 9 = 2019) W = Week (ex: a = week 27; z represents week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Kev

Year	2019	2020	2021	2022	2023	2024	2025	2026	2027		
Code	9	0	1	2	3	4	5	6	7		
Week	1-26			27-52			53				
Code		A-Z	A-Z		A-Z		a-z		Z		
Internal Code	Sun	Mor	n	Tue Wed		Thu		Fri	Sat		
Code	Т	U		V	W	Х		Y	Z		



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V _{DSS}	-20	V		
Gate-Source Voltage	Vgss	±8	V		
Continuous Drain Current (Note 6) V _{GS} = -4.5V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	-3.2 -2.5	А
Maximum Continuous Body Diode Forward Current (No		ls	-1.9	A	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		ldм	-22	A	
Avalanche Current (Note 7) L = 0.1mH	I _{AS}	-11	A		
Avalanche Energy (Note 7) L = 0.1mH			Eas	7	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	0.79	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	159	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	PD	1.39	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Rəja	90	°C/W
Operating and Storage Temperature Range	•	TJ, TSTG	-55 to +150	°C

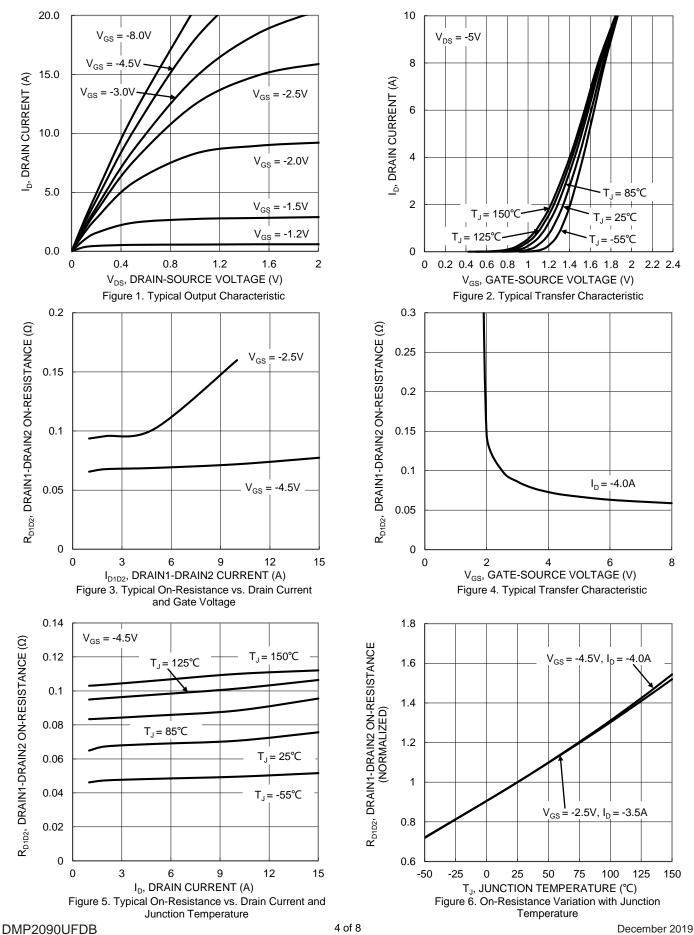
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)	Cymbol		1 JP	max	onit	
Drain-Source Breakdown Voltage	BV _{DSS}	-20	_		V	Vgs = 0V, Ip = -250µA
Zero Gate Voltage Drain Current TJ = +25°C	IDSS	—	_	-1.0	μA	$V_{DS} = -20V, V_{GS} = 0V$
Gate-Source Leakage	lgss	_	_	±10	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)	•	•	•		•	•
Gate Threshold Voltage	Vgs(th)	-0.3	_	-1.0	V	VDS = VGS, ID = -250µA
Statis Drain 1 Drain 2 On Desistance	5	—	37	90		VGS = -4.5V, ID = -4A
Static Drain1-Drain2 On-Resistance	RD1D2	_	50	120	mΩ	V _{GS} = -2.5V, I _D = -3.5A
Diode Forward Voltage	Vsd	—	-0.7	-1.2	V	VGS = 0V, IS = -1.0A
DYNAMIC CHARACTERISTICS (Note 9)	•	•	•		•	•
Input Capacitance	Ciss	—	634	_	pF	
Output Capacitance	Coss	—	81	—	pF	$V_{DS} = -10V, V_{GS} = 0V,$ - f = 1.0MHz
Reverse Transfer Capacitance	Crss	—	66	—	pF	
Gate Resistance	Rg	—	20	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = -4.5V)	Qg	—	6.8	—	nC	
Gate-Source Charge	Qgs	—	0.7	—	nC	V _{DS} = -4.5V, I _D = -4A, V _{DS} = -10V
Gate-Drain Charge	Q _{gd}	—	1.6	—	nC	$\nabla DS = -10V$
Turn-On Delay Time	td(on)		4.2		ns	
Turn-On Rise Time	tR	_	3.4	_	ns	V _{DS} = -10V, V _{GS} = -4.5V,
Turn-Off Delay Time	tD(OFF)	—	23	—	ns	$R_L = 3.3\Omega, R_g = 1\Omega$
Turn-Off Fall Time	tF	—	9.6	—	ns	7
Body Diode Reverse Recovery Time	t _{RR}	—	1.8	—	ns	I _S = -1.0A, dI/dt = 100A/µs
Body Diode Reverse Recovery Charge	Q _{RR}		9.4		nC	I _S = -1.0A, dl/dt = 100A/µs

5. Device mounted on FR-4 substrate PCB, 2oz copper, with minimum recommended pad layout. 6. Device mounted on FR-4 substrate PCB, 2oz copper, with 1inch square copper plate. 7. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}$ C. Notes:

Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.



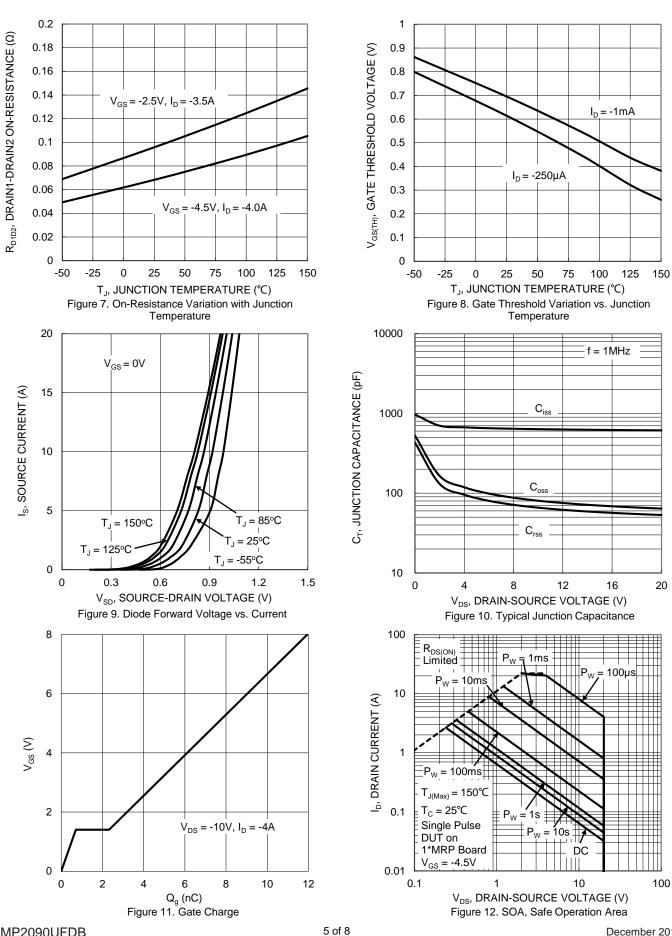


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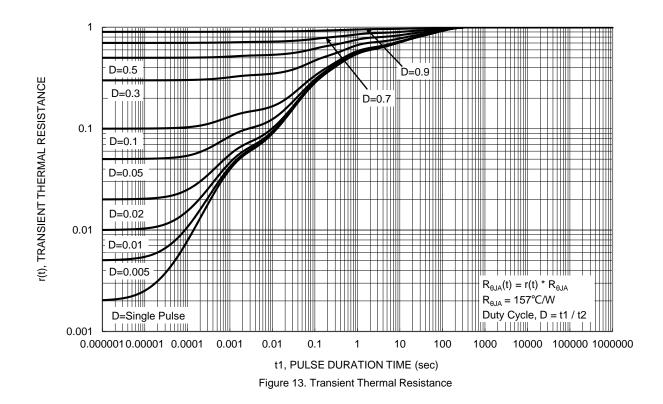
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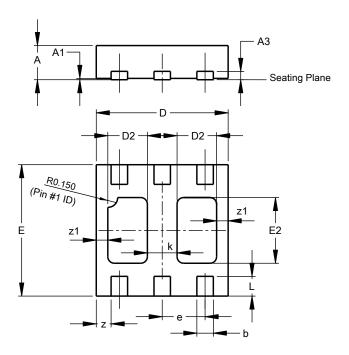






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



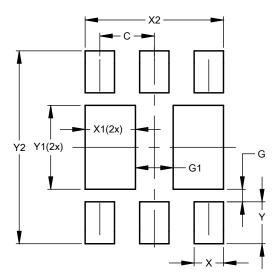
U-DFN2020-6 (Type B)

	U-DFN2020-6 Type B							
Dim	Min	Max	Тур					
Α	0.545	0.605	0.575					
A1	0.00	0.05	0.02					
A3	-	-	0.13					
b	0.20	0.30	0.25					
D	1.95	2.075	2.00					
D2	0.50	0.70	0.60					
е	-	-	0.65					
Е	1.95	2.075	2.00					
E2	0.90	1.10	1.00					
k	-	-	0.45					
L	0.25	0.35	0.30					
z	-	-	0.225					
z1	-	-	0.175					
All	Dimens	ions in	mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type B)



Dimensions	Value (in mm)
С	0.650
G	0.150
G1	0.450
Х	0.350
X1	0.600
X2	1.650
Ý	0.500
Y1	1.000
Y2	2.300



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